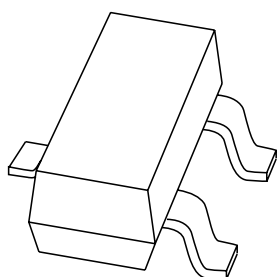


# DATA SHEET



**PMBTA56**

**PNP general purpose transistor**

Product specification  
Supersedes data of 1999 Apr 09

2004 Jan 09

## PNP general purpose transistor

## PMBTA56

## FEATURES

- High current (max. 500 mA)
- Low voltage (max. 80 V).

## APPLICATIONS

- General purpose switching and amplification, e.g. telephony and professional communication equipment.

## DESCRIPTION

PNP transistor in a SOT23 plastic package.  
NPN complement: PMBTA06.

## MARKING

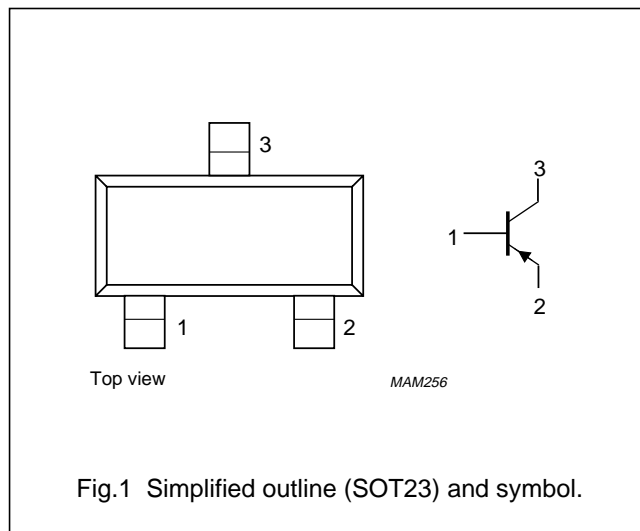
TYPE NUMBER	MARKING CODE <sup>(1)</sup>
PMBTA56	*2G

## Note

- \* = p : Made in Hong Kong.  
\* = t : Made in Malaysia.  
\* = W : Made in China.

## PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



## ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
PMBTA56	—	plastic surface mounted package; 3 leads	SOT23

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	—	–80	V
$V_{CEO}$	collector-emitter voltage	open base	—	–80	V
$V_{EBO}$	emitter-base voltage	open collector	—	–5	V
$I_C$	collector current (DC)		—	–500	mA
$I_{CM}$	peak collector current		—	–1	A
$I_{BM}$	peak base current		—	–200	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$ ; note 1	—	250	mW
$T_{stg}$	storage temperature		–65	+150	°C
$T_j$	junction temperature		—	150	°C
$T_{amb}$	operating ambient temperature		–65	+150	°C

## Note

1. Transistor mounted on an FR4 printed-circuit board.

## PNP general purpose transistor

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## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th(j-a)}$	thermal resistance from junction to ambient	note 1	500	K/W

## Note

1. Transistor mounted on an FR4 printed-circuit board.

## CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$I_{CBO}$	collector cut-off current	$I_E = 0$ ; $V_{CB} = -80\text{ V}$	–	–50	nA
$I_{EBO}$	emitter cut-off current	$I_C = 0$ ; $V_{EB} = -5\text{ V}$	–	–50	nA
$h_{FE}$	DC current gain	$I_C = -10\text{ mA}$ ; $V_{CE} = -1\text{ V}$	100	–	
		$I_C = -100\text{ mA}$ ; $V_{CE} = -1\text{ V}$	100	–	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = -100\text{ mA}$ ; $I_B = -10\text{ mA}$	–	–250	mV
$V_{BE}$	base-emitter voltage	$I_C = -100\text{ mA}$ ; $V_{CE} = -1\text{ V}$	–	–1.2	V
$f_T$	transition frequency	$I_C = -100\text{ mA}$ ; $V_{CE} = -1\text{ V}$ ; $f = 100\text{ MHz}$	50	–	MHz

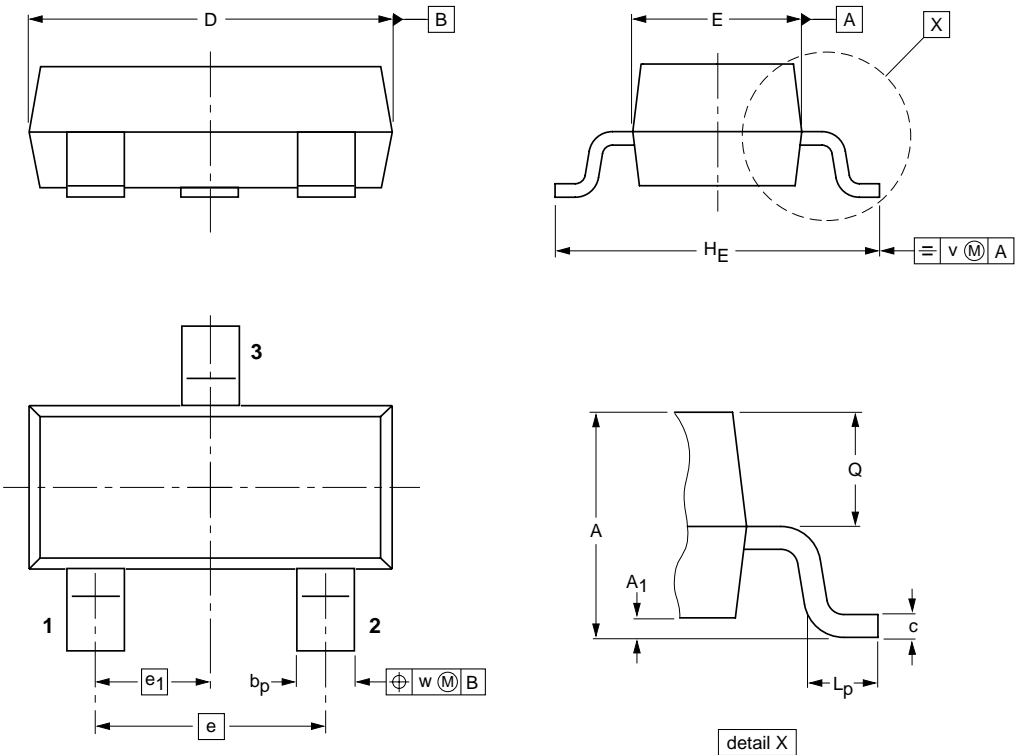
PNP general purpose transistor

PMBTA56

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A <sub>1</sub> max.	b <sub>p</sub>	c	D	E	e	e <sub>1</sub>	H <sub>E</sub>	L <sub>p</sub>	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT23		TO-236AB				97-02-28 99-09-13

## PNP general purpose transistor

## PMBTA56

## DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

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3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

**Limiting values definition** — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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